



DMP2067LSS

Product Summary

BV _{DSS}	Rds(on) Max	I _D Max T _A = +25°C		
-20V	38mΩ @ V _{GS} = -4.5V	-5.4A		
	56mΩ @ V _{GS} = -2.5V	-4.4A		

Description and Applications

This MOSFET is designed to minimize the on-state resistance (RDs(ON)) yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

- Backlighting
- Power management functions
- DC-DC converters

Features and Benefits

- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)

P-CHANNEL ENHANCEMENT MODE MOSFET

- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative.

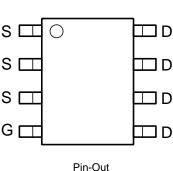
https://www.diodes.com/quality/product-definitions/

Mechanical Data

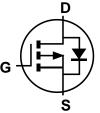
- Package: SO-8
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals Connections: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.072g (Approximate)



Top View



Top View



Equivalent Circuit

Ordering Information (Note 4)

Dort Number	Deckere	Packing		
Part Number	Package	Qty.	Carrier	
DMP2067LSS-13	SO-8	2500	Tape & Reel	

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

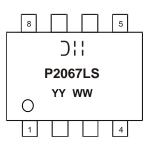
2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

Notes:



)|| = Manufacturer's Marking P2067LS = Product Type Marking Code YYWW = Date Code Marking YY or \overline{YY} = Year (ex: 22 = 2022) WW = Week (01 to 53)



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage	V _{DSS}	-20	V		
Gate-Source Voltage			Vgss	±8	V
Continuous Drain Current (Note 6) V_{GS} = -4.5V	Steady State	T _A = +25°C T _A = +70°C	ID	-5.4 -3.2	А
Continuous Drain Current (Note 7) V_{GS} = -4.5V	Steady State	Tc = +25°C T _C = +70°C	lo	-12.9 -10.4	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)			Ідм	-30	А
Continuous Source-Drain Diode Current (Note 6)	ls	-1.4	А		
Avalanche Current, L= 0.1mH (Note 10)			las	-18.7	А
Avalanche Energy, L= 0.1mH (Note 10)			Eas	17.5	mJ

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	T _A = +25°C	PD	1.2	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	RθJA	104	°C/W
Total Power Dissipation (Note 6)	T _A = +25°C	PD	1.67	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	RθJA	75	°C/W
Thermal Resistance, Junction to Case (Note 7)	Steady State	R _{0JC}	14	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

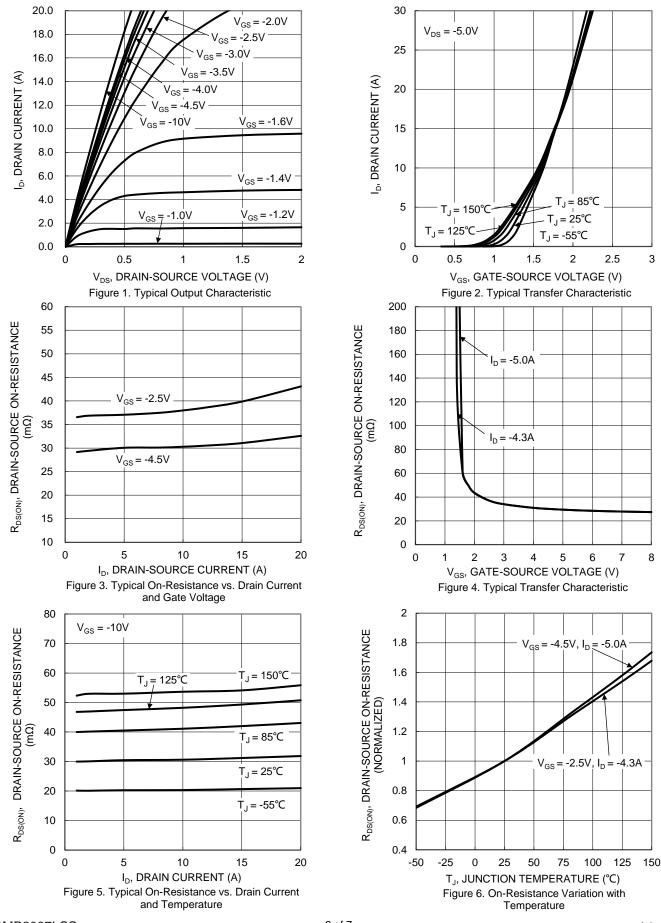
Electrical Characteristics (T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 8)			•	•	•	·
Drain-Source Breakdown Voltage	BVDSS	-20	—	—	V	$V_{GS} = 0V, I_{D} = -250 \mu A$
Zero Gate Voltage Drain Current	IDSS	_	—	-100	nA	V _{DS} = -16V, V _{GS} = 0V
Gate-Source Leakage	lgss	_	—	±100	nA	$V_{GS} = \pm 8V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 8)	·					•
Gate Threshold Voltage	V _{GS(TH)}	-0.5	—	-1.5	V	$V_{DS} = V_{GS}, I_D = -250 \mu A$
Static Drain-Source On-Resistance	Descer	_	31	38	mΩ	VGS = -4.5V, ID = -5A
Static Drain-Source On-Resistance	RDS(ON)	_	37	56	11152	VGS = -2.5V, ID = -4.3A
Diode Forward Voltage	V _{SD}	-0.5	-0.7	-1.2	V	V _{GS} = 0V, I _S = -2.1A
DYNAMIC CHARACTERISTICS (Note 9)	·					•
Input Capacitance	Ciss		1575	_		V _{DS} = -10V, V _{GS} = 0V, f = 1.0MHz
Output Capacitance	Coss		124	_	pF	
Reverse Transfer Capacitance	Crss		89	-		
Gate Resistance	Rg	_	10	—	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$
Total Gate Charge (V _{GS} = -4.5V)	Qg	_	27.9	_		
Total Gate Charge (V _{GS} = -8V)	Qg	_	15.5	_	nC	V _{DS} = -10V, I _D = -4.5A
Gate-Source Charge	Q _{gs}	_	1.6	_		
Gate-Drain Charge	Q _{gd}	_	3.4	—		
Turn-On Delay Time	td(ON)		5.2	—		$V_{DD} = -5V, R_L = 6\Omega$ $V_{GS} = -4.5V, R_g = 6\Omega, I_D = -1A$
Turn-On Rise Time	tR		12.2	—		
Turn-Off Delay Time	t _{D(OFF)}		103	_	ns	
Turn-Off Fall Time	tF		30.7	_	1	
Body Diode Reverse Recovery Time	trr		13	_	ns	IF = -8.9A, di/dt = -100A/µs
Body Diode Reverse Recovery Charge	Qrr		6.3	_	nC	IF = -8.9A, di/dt = -100A/µs

Notes: 5. Device mounted on FR-4 PCB, with minimum recommended pad layout, single sided.

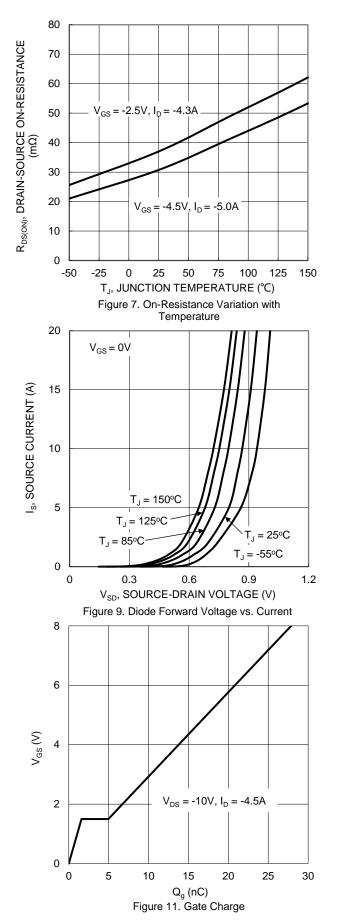
before mounted on FR-4 PCB, with minimum recommended paragout, single sided.
Device mounted on FR-4 substrate PCB, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.
Thermal resistance from junction to soldering point (on the exposed drain pad).
Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to product testing.
I_{AS} and E_{AS} ratings are based on low frequency and duty cycles to keep T_J = +25°C.

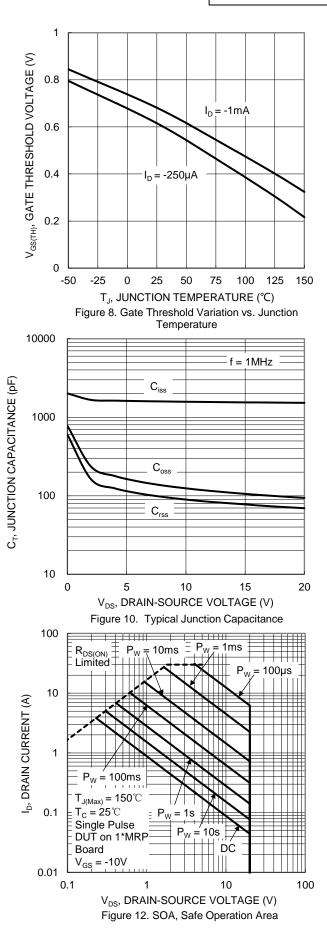




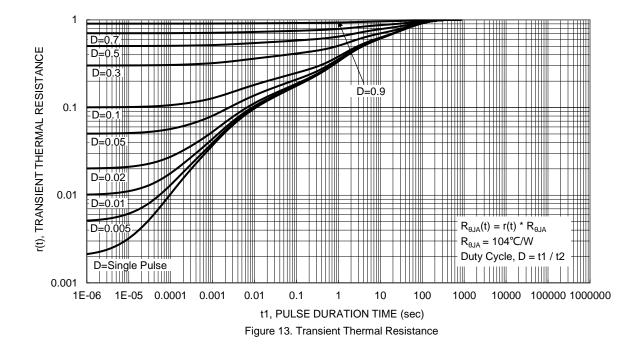
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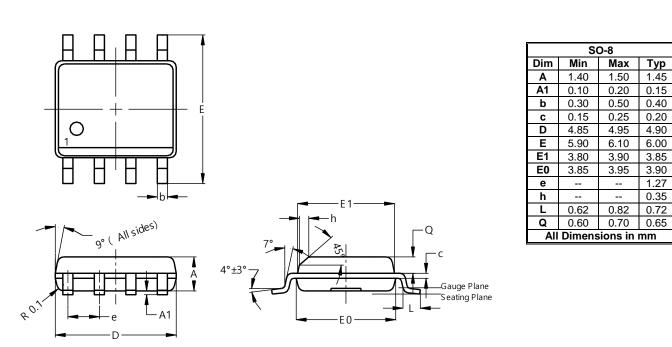






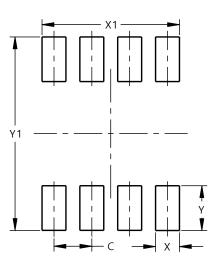
Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.



Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
С	1.27
Х	0.802
X1	4.612
Y	1.505
Y1	6.50

SO-8



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